

SG1825C/SG2825C/SG3825C

HIGH-SPEED CURRENT-MODE PWM

ABSOLUTE MAXIMUM RATINGS (Note 1)

RoHS Peak Package Solder Reflow Temp. (40 sec. max. exp.)	260° (+0, -5)
Input Voltage (V_{IN} and V_C)	30V
Analogue Inputs:	
Error Amplifier and Ramp	-0.3V to 7.0V
Softstart and $I_{LIM}/S.D.$	-0.3V to 6.0V
Digital Input (Clock)	1.5V to 6.0V
Driver Outputs	-0.3V to $V_C+1.5V$
Source / Sink Output Current (each output):	
Continuous	0.5A
Pulse, 500ns	2.0A
Softstart Sink Current	20mA
Clock Output Current	5mA
Error Amplifier Output Current	5mA
Oscillator Charging Current	5mA
Operating Junction Temperature:	
Hermetic (J, L Package)	150°C
Plastic (DW, N, Q Packages)	150°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (soldering, 10 seconds)	300°C

Note 1. Exceeding these ratings could cause damage to the device.

THERMAL DATA

N PACKAGE:

THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	65°C/W
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DW PACKAGE:

THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	95°C/W
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Q PACKAGE:

THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	80°C/W
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J PACKAGE:

THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	80°C/W
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L PACKAGE:

THERMAL RESISTANCE-JUNCTION TO CASE, θ_{JC}	35°C/W
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THERMAL RESISTANCE-JUNCTION TO AMBIENT, θ_{JA}	120°C/W
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Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

The θ_{JA} numbers are guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

PACKAGE PIN OUTS

INV. INPUT	1	16	V_{REF}
N.I. INPUT	2	15	$+V_{IN}$
E/A OUTPUT	3	14	OUTPUT B
CLOCK	4	13	V_C
R_T	5	12	PWR GND
C_T	6	11	OUTPUT A
RAMP	7	10	GROUND
SOFTSTART	8	9	$I_{LIM}/S.D.$

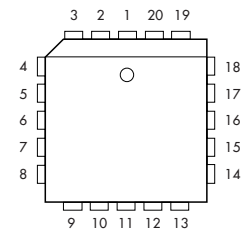
J & N* PACKAGE

(Top View)

INV. INPUT	1	16	$+V_{REF}$
N.I. INPUT	2	15	$+V_{IN}$
E/A OUTPUT	3	14	OUTPUT B
CLOCK	4	13	V_C
R_T	5	12	PWR GND
C_T	6	11	OUTPUT A
RAMP	7	10	GROUND
SOFTSTART	8	9	$I_{LIM}/S.D.$

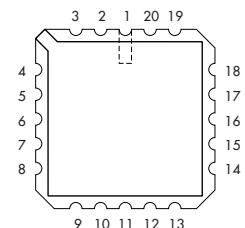
DW PACKAGE*

(Top View)



Q PACKAGE

(Top View)



L PACKAGE

(Top View)

1. N.C.	11. N.C.
2. INV. INPUT	12. $I_{LIM}/S.D.$
3. N.I. INPUT	13. GROUND
4. E/A OUTPUT	14. OUTPUT A
5. CLOCK	15. PWR GND
6. N.C.	16. N.C.
7. R_T	17. V_C
8. C_T	18. OUTPUT B
9. RAMP	19. $+V_{IN}$
10. SOFTSTART	20. V_{REF}

*DW & N Packages: RoHS / Pb-free 100% Matte Tin Lead Finish

SG1825C/SG2825C/SG3825C

HIGH-SPEED CURRENT-MODE PWM

RECOMMENDED OPERATING CONDITIONS (Note 2)

Parameter	Symbol	Recommended Operating Conditions			Units
		Min.	Typ.	Max.	
Supply Voltage Range		10		30	V
Voltage Amp Common Mode Range		1.5		5.5	V
Ramp Input Voltage Range		0		5.0	V
Current Limit / Shutdown Voltage Range		0		4.0	V
Source / Sink Output Current					
Continuous			200		mA
Pulse, 500ns			1.0		A
Voltage Reference Output Current		1		10	mA
Oscillator Frequency Range		4		1500	kHz
Oscillator Charging Current		0.030		3	mA
Oscillator Timing Resistor	R_T	1		100	k Ω
Oscillator Timing Capacitor	C_T	0.470		10	nF
Operating Ambient Temperature Range:					
SG1825C	T_A	0		70	$^{\circ}\text{C}$
SG2825C	T_A	-25		85	$^{\circ}\text{C}$
SG3825C	T_A	-55		125	$^{\circ}\text{C}$

Note 2. Range over which the device is functional.

ELECTRICAL CHARACTERISTICS (Note 3)

(Unless otherwise specified, these specifications apply over the operating ambient temperatures for SG3825C with $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, SG2825C with $-25^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, SG1825C with $-55^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$, and $V_{IN}=V_C=15\text{V}$. Low duty cycle pulse testing techniques are used which maintains junction and case temperatures equal to the ambient temperature.)

Parameter	Symbol	Test Conditions	SG1825C/2825C			SG3825C			Units
			Min.	Typ.	Max.	Min.	Typ.	Max.	

Reference Section

Output Voltage		$T_J = 25^{\circ}\text{C}, I_L = 1\text{mA}$	5.05	5.10	5.15	5.05	5.10	5.15	V
Line Regulation		$V_{IN} = 10 \text{ to } 30\text{V}$		2	15		2	15	mV
Load Regulation		$I_L = 1 \text{ to } 10\text{mA}$		5	15		5	15	mV
Temperature Stability (Note 3)		Over Operating Temperature		0.2	0.4		0.2	0.4	mV/ $^{\circ}\text{C}$
Total Output Range (Note 3)		Over Line, Load, and Temperature	5.00		5.20	5.00		5.20	V
Output Noise Voltage (Note 3)		$f = 10\text{Hz to } 10\text{kHz}, I_L = 0\text{mA}$		50	200		50		μV_{RMS}
Long Term Stability (Notes 3 & 4)		$T_J = 125^{\circ}\text{C}, t = 1000\text{hrs}$		5	25		5	25	mV
Short Circuit Current		$V_{\text{REF}} = 0\text{V}$	-15	-50	-100	-15	-50	-100	mA

Oscillator Section (Note 5)

Initial Accuracy		$T_J = 25^{\circ}\text{C}, C_{\text{CLK}} \leq 10\text{pF}$	370	400	430	370	400	430	kHz
Voltage Stability		$V_{IN} = 10 \text{ to } 30\text{V}$		0.2	2		0.2	2	%
Temperature Stability (Note 3)		Over Rated Operating Temperature		5	8		5	8	%
Total Frequency Limits (Note 3)		Over Line and Temperature	350		450	350		450	kHz
Minimum Frequency		$R_T = 100\text{k}\Omega, C_T = 0.01\mu\text{F}$			4			4	kHz
Maximum Frequency		$R_T = 1\text{k}\Omega, C_T = 470\text{pF}$	1.5			1.5			MHz
Clock High Level		$I_{\text{CLK}} = -1\text{mA}$	3.9	4.5		3.9	4.5		V
Clock Low Level		$I_{\text{CLK}} = -1\text{mA}$		2.3	2.9		2.3	2.9	V
Ramp Peak Voltage			2.6	2.8	3.0	2.6	2.8	3.0	V
Ramp Valley Voltage			0.7	1.0	1.25	0.7	1.0	1.25	V
Valley-to-Peak Amplitude			1.6	1.8	2.0	1.6	1.8	2.0	V

Note 3. This parameter is guaranteed by design and process control, but is not 100% tested in production.

Note 4. This parameter is non-accumulative, and represents the random fluctuation of the reference voltage within some error band when observed over any 1000 hour period of time.

ELECTRICAL CHARACTERISTICS (Cont'd.)

Parameter	Symbol	Test Conditions	SG1825C/2825C			SG3825C			Units
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Error Amplifier Section (Note 6)									
Input Offset Voltage		$R_s \leq 2K\Omega$, $V_{ERROR} = 2.5V$			15			15	mV
Input Bias Current		$V_{ERROR} = 2.5V$		0.6	3		0.6	3	μA
Input Offset Current		$V_{ERROR} = 2.5V$		0.1	1		0.1	1	μA
DC Open Loop Gain	A_{VOL}	$V_{ERROR} = 1$ to $4V$	60	95		60	95		dB
Common Mode Rejection		Over Rated Voltage Range, $V_{ERROR} = 2.5V$	75	95		75	95		dB
Power Supply Rejection		$V_{IN} = 10V$ to $30V$, $V_{ERROR} = 2.5V$	85	110		85	110		dB
Output Sink Current		$V_{ERROR} = 1V$	1	2.5		1	2.5		mA
Output Source Current		$V_{ERROR} = 4V$	-0.5	-1.3		-0.5	-1.3		mA
Output High Voltage		$I_{ERROR} = -0.5mA$	4.0	4.7	5.0	4.0	4.7	5.0	V
Output Low Voltage		$I_{ERROR} = 1mA$	0	0.5	1.0	0	0.5	1.0	V
Unity Gain Bandwidth (Note 3)		$A_{VOL} = 0dB$	3	5.5		3	5.5		MHz
Slew Rate (Note 3)			6			6			V/ μsec
PWM Comparator Section (Note 5 & 7)									
Ramp Input Bias Current				-1	-5		-1	-5	μA
Minimum Duty Cycle		$V_{ERROR} = 1V$			0			0	%
Maximum Duty Cycle (Note 8)		$V_{ERROR} = 4V$	85			85			%
Zero Duty Cycle Threshold			1.1	1.25		1.1	1.25		V
Delay to Driver Output (Note 3)		$V_{RAMP} = 0V$ to $2V$, $V_{ERROR} = 2V$		50	80		50	80	ns
Softstart Section									
C_{SS} Charge Current		$V_{SOFTSTART} = 0.5V$	3	9	20	3	9	20	μA
C_{SS} Discharge Current		$V_{SOFTSTART} = 1.0V$	1			1			mA
Current Limit / Shutdown Section (Note 9)									
I_{LIM} Input Bias Current					± 15			± 10	μA
Current Limit Threshold			0.9	1.0	1.1	0.9	1.0	1.1	V
Shutdown Threshold			1.25	1.40	1.55	1.20	1.40	1.55	V
Delay to Driver Output (Note 3)		$V_{SHUTDOWN} = 0V$ to $1.2V$		50	80		50	80	ns
Output Drivers Section (each output)									
Output Low Level		$I_{SINK} = 20mA$		0.25	0.40		0.25	0.40	V
		$I_{SINK} = 200mA$		1.2	2.0		1.2	2.0	V
Output High Level		$I_{SOURCE} = 20mA$	13.0	13.5		13.0	13.5		V
		$I_{SOURCE} = 200mA$	12.0	13.0		12.0	13.0		V
V_C Standby Current		$V_C = 30V$		150	500		150	500	μA
Output Rise / Fall Time (Note 3)		$C_L = 1000pF$		30	60		30	60	ns
Undervoltage Lockout Section									
Start Threshold Voltage			8.8	9.2	9.7	8.8	9.2	9.7	V
UV Lockout Hysteresis			0.4	0.8	1.2	0.4	0.8	1.2	V
Supply Current Section (Note 5)									
Start Up Current		$V_{IN} = 8V$		0.5	1.2		0.5	1.2	mA
Operating Current		V_{INV} , V_{RAMP} , $V(I_{LIM}/S.D.) = 0V$, $V_{NL} = 1V$		22	33		22	33	mA

Note 5. $F_{OSC} = 400kHz$ ($R_T = 3.65k\Omega$, $C_T = 1.0nF$).Note 6. $V_{CM} = 1.5V$ to $5.5V$.Note 7. $V_{RAMP} = 0V$, unless otherwise specified.

Note 8. 100% duty cycle is defined as a pulsewidth equal to one oscillator period.

Note 9. $V(I_{LM}/S.D.) = 0V$ to $4.0V$, unless otherwise specified.

BLOCK DIAGRAM

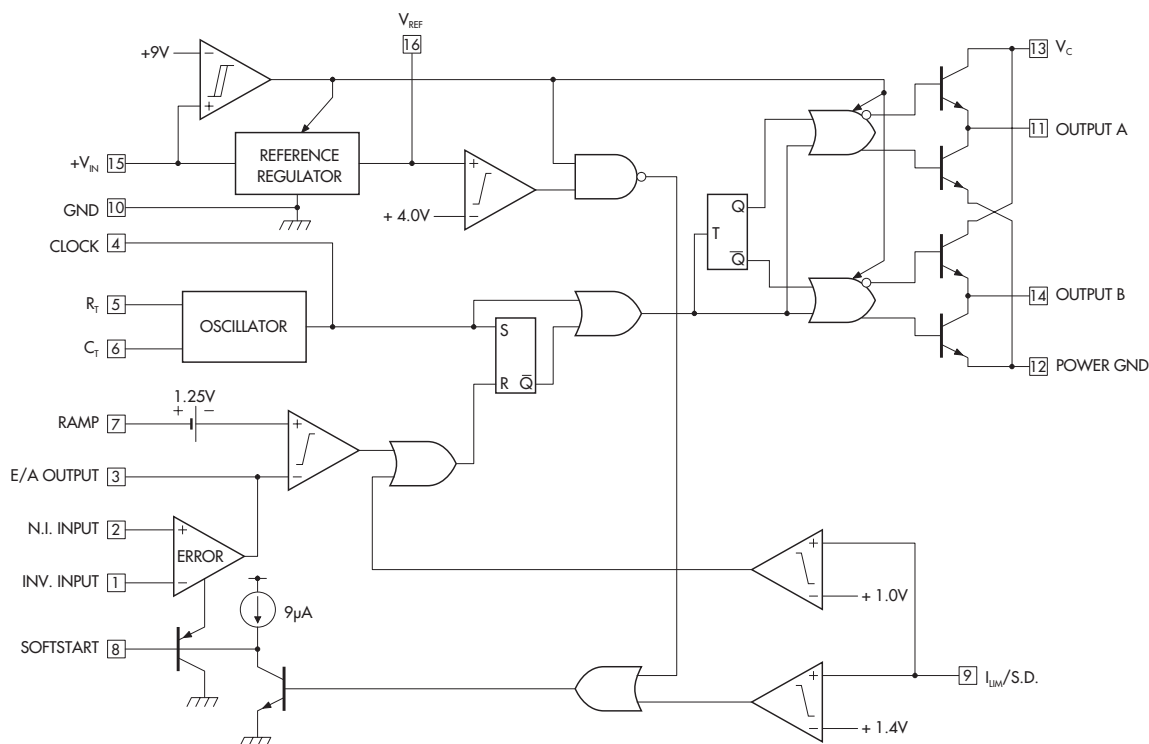


FIGURE INDEX

Application Circuits

FIGURE

1. HIGH-SPEED LAYOUT AND BYPASSING
2. MICROPOWER STARTUP
3. SOFTSTART FAST RESET
4. OSCILLATOR SYNCHRONIZATION
5. OSCILLATOR FUNCTIONAL DIAGRAM
6. VOLTAGE AMPLIFIER CONNECTIONS
7. DRIVING SHIELDED CABLE

APPLICATION INFORMATION

OSCILLATOR

The oscillator frequency is programmed by external timing components R_T and C_T . A nominal +3.0 volts appears at the R_T pin. The current flowing through R_T is mirrored internally with a 1:1 ratio. This causes an identical current to flow out the C_T pin, charging the timing capacitor and generating a linear ramp. When the upper threshold of +2.8 volts is reached, a discharge network reduces the ramp voltage to +1.0, where a new charge cycle begins.

The Clock output pin is LOW (+2.3 volts) during the charge cycle, and HIGH (+4.5 volts) during the discharge cycle. The Clock pin is driven by an NPN emitter follower, and so can be wire-ORed. Each Clock pin can drive a 1mA load. Since the internal current-source pulldown is approximately 400 μ A, the DC fan-out to other SG1825C Clock pins is at least two.

The type of capacitor selected for C_T is very important. At high frequencies, non-ideal characteristics such as effective series resistance (ESR), effective series inductance (ESL), dielectric loss and dielectric absorption all affect frequency accuracy and stability. RF capacitors such as silver mica, glass, polystyrene, or COG ceramics are recommended. Avoid high-K ceramics, which work best in DC bypass applications.

ERROR AMPLIFIER

The voltage error amplifier is a true operational amplifier with low-impedance output, and can be gain-stabilized using conventional feedback techniques. The typical DC open-loop gain is 95dB, with a single low-frequency pole at 100Hz.

The input connections to the error amplifier are determined by the polarity of the power supply output voltage. For positive supplies, the common-mode voltage is +5.1 volts and the feedback connections in Figure A are used. With negative outputs, the common-mode voltage is half the reference, and the feedback divider is connected between the negative output and the +5.1 volt reference as shown in Figure B.

OUTPUT DRIVER

The output drivers are designed to provide up to 1.5 Amps peak output current. To minimize ringing on the output waveform, which can be destructive to both the power MOSFET and the PWM chip, the series inductance seen by the drivers should be as low as possible.

One solution is to keep the distance between the PWM and MOSFET gate as short as possible, and to use carbon composition series damping resistors. A Faraday shield to intercept radiated EMI from the power transistors is usually required with its choice.

A second approach is to place the MOSFETs some distance from the PWM chip, and use a series-terminated transmission line to preserve drive pulse fidelity. This will minimize noise radiated back to the sensitive analog circuitry of the SG1825C. A Faraday shield may also be required.

If the drivers are connected to an isolation transformer, or if kickback through C_{GD} of the MOSFET is severe, clamp diodes may be required. 1 Amp peak Schottky diodes will limit undershoot to less than -0.3 volts.

APPLICATION FIGURES

FIGURE 5. — OSCILLATOR FUNCTIONAL DIAGRAM

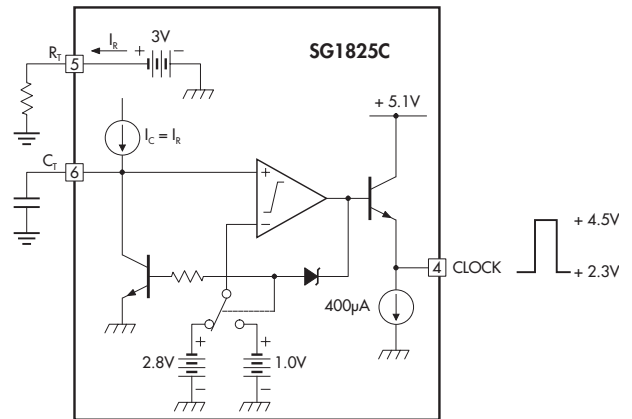


FIGURE 6. — VOLTAGE AMPLIFIER CONNECTIONS

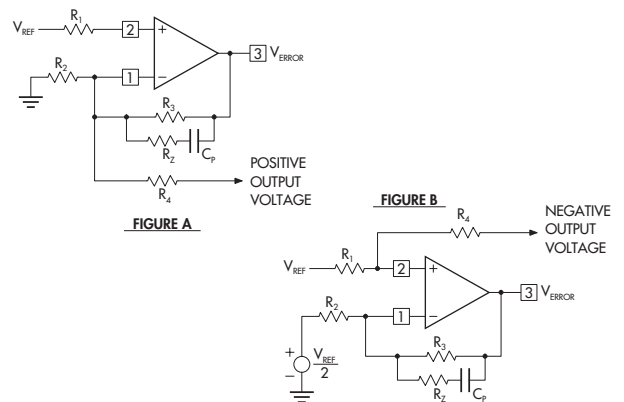


FIGURE 7. — DRIVING SHIELDED CABLE

